







SN74LV20A

SCES339F - SEPTEMBER 2000 - REVISED MAY 2024

SN74LV20A Dual 4-Input Positive-NAND Gate

1 Features

- Operation of 2V to 5.5V V_{CC}
- Max t_{nd} of 6ns at 5V
- Typical V_{OLP} (output ground bounce) < 0.8V at V_{CC} $= 3.3V, T_A = 25^{\circ}C$
- Typical V_{OHV} (output V_{OH} undershoot) > 2.3V at $V_{CC} = 3.3V$, TA = 25°C
- I_{off} supports partial-power-down mode operation
- Latch-up performance exceeds 100mA per JESD 78, Class II

2 Description

These dual 4-input positive-NAND gates are designed for 2V to 5.5V V_{CC} operation.

Package Information

PART NUMBER	PACKAGE ⁽¹⁾	PACKAGE SIZE ⁽²⁾	BODY SIZE(3)
	DGV (TVSOP, 14)	3.60mm x 6.4mm	3.60mm x 4.4mm
	D (SOIC, 14)	8.65mm x 6mm	8.65mm x 3.9mm
SN74LV20A	NS (SOP, 14)	10.20mm x 7.8mm	10.3mm x 5.3mm
	DB (SSOP, 14)	6.20mm x 7.8mm	6.20mm x 5.3mm
	PW (TSSOP, 14)	5.00mm x 6.4mm	5.00mm x 4.4mm

- For more information, see Section 10.
- The package size (length × width) is a nominal value and includes pins, where applicable.
- The body size (length × width) is a nominal value and does not include pins.

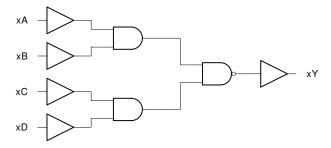




Table of Contents

1 Features1	6.1 Overview	8
2 Description1	6.2 Functional Block Diagram	8
3 Pin Configuration and Functions3	6.3 Device Functional Modes	8
4 Specifications4	7 Application and Implementation	9
4.1 Absolute Maximum Ratings4	7.1 Power Supply Recommendations	9
4.2 ESD Ratings4	7.2 Layout	
4.3 Recommended Operating Conditions4	8 Device and Documentation Support	
4.4 Thermal Information5	8.1 Documentation Support (Analog)	10
4.5 Electrical Characteristics5	8.2 Receiving Notification of Documentation Updates	10
4.6 Switching Characteristics, V _{CC} = 2.5 V ± 0.2 V5	8.3 Support Resources	10
4.7 Switching Characteristics, V _{CC} = 3.3 V ± 0.3 V6	8.4 Trademarks	
4.8 Switching Characteristics, V _{CC} = 5 V ± 0.5 V6	8.5 Electrostatic Discharge Caution	10
4.9 Noise Characteristics6	8.6 Glossary	
4.10 Operating Characteristics6	9 Revision History	
5 Parameter Measurement Information7	10 Mechanical, Packaging, and Orderable	
6 Detailed Description8	Information	10

3 Pin Configuration and Functions

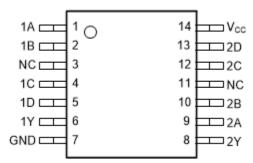


Figure 3-1. SN74LV20A D, DB, DGV, NS, or PW Package; 14-Pin SOIC, SSOP, TVSOP, SOP, or TSSOP (Top View)

Table 3-1. Pin Functions

	PIN	TYPE ⁽¹⁾	DESCRIPTION
NAME	NO.	I TPE("/	DESCRIPTION
1A	1	I	1A Input
1B	2	I	1B Input
NC	3	_	Not internally connected
1C	4	I	1C Input
1D	5	I	1D Input
1Y	6	0	1Y Output
2Y	8	0	2Y Output
2A	9	I	2A Input
2B	10	I	2B Input
NC	11	_	Not internally connected
2C	12	I	2C Input
2D	13	I	2D Input
GND	7	_	Ground Pin
V _{CC}	14	_	Power Pin

⁽¹⁾ Signal Types: I = Input, O = Output.



4 Specifications

4.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

	<u> </u>	·	MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.5	7	V
VI	Input voltage range ⁽²⁾		-0.5	7	V
Vo	Output voltage range applied	in high or low state ^{(2) (3)}	-0.5	V _{CC} + 0.5	V
Vo	Output voltage range applied	in power-off state ⁽²⁾	-0.5	7	V
I _{IK}	Input clamp current	(V _I < 0)		-20	mA
I _{OK}	Output clamp current	(V _O < 0)		-50	mA
Io	Continuous output current	$(V_O = 0 \text{ to } V_{CC})$		±25	mA
	Continuous current through V	CC or GND		±50	mA
TJ	Junction Temperature			150	°C
T _{stg}	Storage temperature		-65	150	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

4.2 ESD Ratings

			VALUE	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1)	±2000	
V _(ESD)	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾	±1000	V

⁽¹⁾ JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

4.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

			MIN	MAX	UNIT	
V _{CC}	Supply voltage		2	5.5	V	
		V _{CC} = 2 V	1.5			
١,,	High level input valtage	V _{CC} = 2.3 V to 2.7 V	V _{CC} × 0.7		V	
V _{IH}	High level input voltage	V _{CC} = 3 V to 3.6 V	V _{CC} × 0.7		V	
		V _{CC} = 4.5 V to 5.5 V	V _{CC} × 0.7			
		V _{CC} = 2 V		0.5		
./ Low le	Low lovel input veltage	V _{CC} = 2.3 V to 2.7 V		V _{CC} × 0.3	V	
V _{IL}	Low level input voltage	V _{CC} = 3 V to 3.6 V		V _{CC} × 0.3	V	
		V _{CC} = 4.5 V to 5.5 V		V _{CC} × 0.3		
V _I	Input voltage		0	5.5	V	
V _O	Output voltage		0	V _{CC}	V	
		V _{CC} = 2 V		-50	μA	
I _{OH} High level output current	High lavel autout august	V _{CC} = 2.3 V to 2.7 V		-2		
	High level output current	V _{CC} = 3 V to 3.6 V		-6	mA	
		V _{CC} = 4.5 V to 5.5 V		-12		

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⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽³⁾ This value is limited to 5.5 V maximum.

⁽²⁾ JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

4.3 Recommended Operating Conditions (continued)

over operating free-air temperature range (unless otherwise noted)(1)

			MIN MAX	UNIT	
		V _{CC} = 2 V	50	μΑ	
I _{OL} Lo	Low level output current	V _{CC} = 2.3 V to 2.7 V	2		
	Low level output current	V _{CC} = 3 V to 3.6 V	6	mA	
		V _{CC} = 4.5 V to 5.5 V	12		
		V _{CC} = 2.3 V to 2.7 V	200		
Δt/Δν	Input transition rise and fall rate	V _{CC} = 3 V to 3.6 V	100	ns/V	
		V _{CC} = 4.5 V to 5.5 V	20		
T _A	Operating free-air temperature		-40 85	°C	

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004

4.4 Thermal Information

		SN74LV20A					
	THERMAL METRIC(1)	D	DB	DGV	NS	PW	UNIT
		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	86	96	127	76	113	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

4.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	V _{cc}	MIN	TYP MA	K UNIT
		$I_{OH} = -50 \mu A$	2 V to 5.5 V	V _{CC} - 0.1		
\ <u>\</u>	High-level output voltage	I _{OH} = -2 mA	2.3 V	2		V
V _{OH}	OH Trigit-level output voitage	I _{OH} = -6 mA	3 V	2.48		V
		I _{OH} = -12 mA	4.5 V	3.8		
	V	I _{OL} = 50 μA	2 V to 5.5 V		0.	1
\ <u>\</u>		I _{OL} = 2 mA	2.3 V		0.	4 V
V _{OL}	Low-level output voltage	I _{OL} = 6 mA	3 V		0.4	
		I _{OL} = 12 mA	4.5 V		0.5	5
I _I	Input leakage current	V _I = 5.5 V or GND	0 to 5.5 V		±	1 μΑ
I _{CC}	Supply current	$V_1 = V_{CC}$ or GND, $I_O = 0$	5.5 V		2	0 μΑ
I _{off}	Off-state leakage current	V _I or V _O = 0 to 5.5 V	0 V			5 μΑ
Ci	Input capacitance	V _I = V _{CC} or GND	3.3 V		1.9	pF

4.6 Switching Characteristics, $V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER FROM TO LOAD		Т	A = 25°C		SN74LV20A				
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNIT
t _{pd}	A, B, C or D	Y	C _L = 15 pF		6.8	11.6	1	13.5	ns
t _{pd}	A, B, C or D	Y	C _L = 50 pF		9.2	15.3	1	18.5	115



4.7 Switching Characteristics, $V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	1	T _A = 25°C		SN74L	/20A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	UNII
t _{pd}	A, B, C, or D	Y	C _L = 15 pF		4.9	6.6	1	8	ns
t _{pd}	A, B, C, or D	Y	C _L = 50 pF		6.5	10.1	1	11.5	

4.8 Switching Characteristics, V_{CC} = 5 V ± 0.5 V

over recommended operating free-air temperature range (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM	то	LOAD	1	Γ _A = 25°C		SN74L	/20A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	ONII
t _{pd}	A, B, C, or D	Y	C _L = 15 pF		3.7	5	1	6	ne
t _{pd}	A, B, C, or D	Y	C _L = 50 pF		4.8	7	1	8	ns

4.9 Noise Characteristics

 $V_{CC} = 3.3 \text{ V}, C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$

	PARAMETER ⁽¹⁾	MIN	TYP	MAX	UNIT
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		0	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		3.2		V
V _{IH(D)}	High-level dynamic input voltage	2.31			V
V _{IL(D)}	Low-level dynamic input voltage			0.99	V

⁽¹⁾ Characteristics are for surface-mount packages only.

4.10 Operating Characteristics

 $T_A = 25^{\circ}C$

PARAMETER	TEST C	CONDITIONS	V _{cc}	TYP	UNIT
Power dissipation capacitance	$C_1 = 50 \text{ pF},$	f = 10 MHz	3.3 V	20.5	pF
Power dissipation capacitance	$C_L = 50 \text{ pF},$	1 - 10 WITZ	5 V	23.9	

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5 Parameter Measurement Information

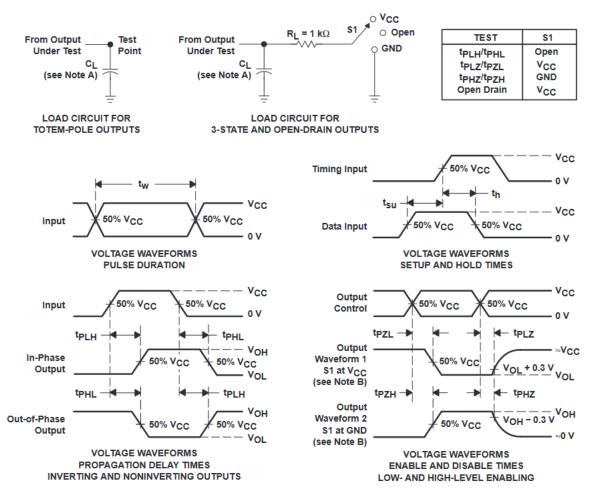


Figure 5-1. Load Circuit and Voltage Waveforms

- A. C_L includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_O = 50 \Omega$, $t_r \leq 3 \text{ ns}$, $t_f \leq 3 \text{ ns}$.
- D. The outputs are measured one at a time, with one input transition per measurement.
- E. t_{PLZ} and t_{PHZ} are the same as t_{dis} .
- F. t_{PZL} and t_{PZH} are the same as t_{en} .
- G. t_{PHL} and t_{PLH} are the same as t_{pd} .
- H. All parameters and waveforms are not applicable to all devices.



6 Detailed Description

6.1 Overview

The SN74LV20A devices perform the Boolean function $Y = \overline{A \cdot B \cdot C \cdot D}$ or $Y = \overline{A} + \overline{B} + \overline{C} + \overline{D}$ in positive logic.

These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs, preventing damaging current backflow through the devices when they are powered down.

6.2 Functional Block Diagram

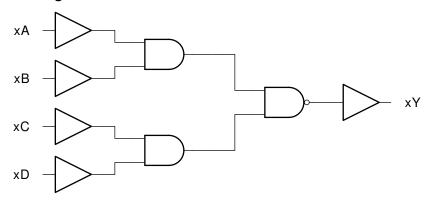


Figure 6-1. logic diagram (positive logic)

6.3 Device Functional Modes

Function Table (each gate)

	OUTPUT			
Α	В	С	D	Υ
Н	Н	Н	Н	L
L	Χ	Χ	Х	Н
Х	L	Χ	Х	Н
Х	Χ	L	Х	Н
X	Χ	Χ	L	Н

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7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1- μ F capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1- μ F and 1- μ F capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

7.2 Layout

7.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.

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8 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

8.1 Documentation Support (Analog)

8.1.1 Related Documentation

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY	
SN74LV20A	Click here	Click here	Click here	Click here	Click here	

8.2 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on Subscribe to updates to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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8.4 Trademarks

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8.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.6 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision E (April 2005) to Revision F (May 2024)

Page

Added Package Information table, Pin Functions table, ESD Ratings table, Thermal Information table, Device Functional Modes, Application and Implementation section, Device and Documentation Support section, and

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Product Folder Links: SN74LV20A

www.ti.com 23-May-2024

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LV20ADBR	ACTIVE	SSOP	DB	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV20A	Samples
SN74LV20ADGVR	ACTIVE	TVSOP	DGV	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV20A	Samples
SN74LV20ADR	ACTIVE	SOIC	D	14	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	LV20A	Samples
SN74LV20ANSR	ACTIVE	SO	NS	14	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 85	74LV20A	Samples
SN74LV20APWR	ACTIVE	TSSOP	PW	14	2000	RoHS & Green	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	LV20A	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

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MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DB (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

28 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-150

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